



Sheet 1 of 1

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	APPLICANTS: HAHN et al.	
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UNITED STATES PATENT DOCUMENTS

EXAM. INITIAL	DOCUMENT NUMBER	DATE	INVENTOR/ASSIGNEE	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
RM	5,610,486	MAR. '97	LI/SGS-THOMSON	318	439	
	5,771,166	JUN. '98	LIM/LG ELECTRONICS	363	132	
RM	5,963,024	OCT. '99	DOEMEN/PAPST	323	282	

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	DOCUMENT NUMBER	DATE	INVENTOR/ASSIGNEE	CLASS	SUBCLASS	TRANSLATION YES/NO
RM	DE 696 07 880-T2	SEP. '96	LI			= USP 5,610,486

OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)

	Patent Abstracts of Japan, English abstract of SATO ++/DAIKIN JP 2001-286-179, OCT. 2001.
RM	Sujit K. BISWAS, Gate Drive Methods for IGBT's in Bridge Configurations, pp. 1310-1316©1994 IEEE document 0-7803-1993-1/94.
	Klaus BENDER et al., TAGUNGSBAND, SPS/IPC-Drives, 28-30 NOV. 2000 Nürnberg, Germany.
RM	LELKES et al., Single-phase External Rotor Synchronous Motor, 9 th European Conf. On Power Electronics and Applications (AUG. 2001).
RM	Fairchild Semiconductor, datasheet on FQD3P50, 500V P-Channel QFET, copyright 2003.
RM	Zetex Semiconductors, NPN High Voltage Transistors, 300 to 500 Volts, FMMT459, copyright 2003.

Examiner

Date:

06/17/2005

NO
TRANSLATION